Influence of the molecular structure on the interface formation between magnesium and organic semiconductors

Braun, W. a, Gavrila, G. b, Gorgoi, M. b, Zahn, D.R.T. b

a BESSY GmbH, Albert-Einstein-Straße 15, Berlin, 12489, Germany
b Institut für Physik, Technische Universität Chemnitz, Chemnitz, 09107, Germany

Abstract

The interface formation between three different perylene derivatives and Mg were investigated by high-resolution soft X-ray photoemission spectroscopy using synchrotron radiation at BESSY. The chemical and electronic properties of these interfaces were obtained after fitting the C \text{1s}, O \text{1s}, N \text{1s} and Mg \text{2p} core-level emission spectra as a function of Mg thickness. A strong chemical interaction between Mg and the molecular end groups is observed leading to the formation of new chemical components and/or charge redistribution due to the presence of the metal. © 2006 Elsevier Ltd. All rights reserved.

Author Keywords

Interfaces; Metal contacts; Organic semiconductors